

TIP111G

TIP111G Information

		-	
WW	w.heis	lener.	com
_	m.		1

Part Number	TIP111G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN DARL 80V 2A TO-220AB
Package	TO-220-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



TIP111G Specifications

Manufacturer Part Number	TIP111G	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	TO-220-3	
Series	-	
Transistor Type	NPN - Darlington	
Current - Collector (Ic) (Max)	2A	
Voltage - Collector Emitter Breakdown (Max)	80V	
Vce Saturation (Max) @ Ib, Ic	2.5V @ 8mA, 2A	
Current - Collector Cutoff (Max)	2mA	
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 1A, 4V	
Power - Max	2W	
Frequency - Transition	-	
Operating Temperature	-65°C ~ 150°C (TJ)	
Mounting Type	Through Hole	
Package / Case	TO-220-3	
Supplier Device Package	TO-220AB	
	Report errors?	

TIP111G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about TIP111G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com